



Denso Proprietary

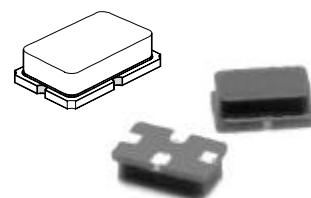
151377-0070

RO2113A-1

- **Ideal for 314.0 MHz Transmitters**
- **Very Low Series Resistance**
- **Quartz Stability**
- **Surface-Mount Ceramic Case with 21 mm<sup>2</sup> Footprint**

The RO2113A-1 is a one-port, surface-acoustic-wave (SAW) resonator in a surface-mount ceramic case. It provides reliable, fundamental-mode, quartz frequency stabilization of local oscillators operating at 314 MHz. Applications include automotive keyless entry receivers operating in the USA under FCC Part 15 and in Canada under DoC RSS-210.

**314.0 MHz  
SAW  
Resonator**



SM-2 Case

#### Absolute Maximum Ratings

Rating	Value	Units
CW RF Power Dissipation	+0	dBm
DC Voltage Between Terminals (Observe ESD Precautions)	±30	VDC
Case Temperature	-40 to +85	°C
Soldering Temperature	+250	°C

#### Electrical Characteristics

Characteristic	Sym	Notes	Minimum	Typical	Maximum	Units
Center Frequency at +25 °C	Absolute Frequency	f <sub>C</sub>	313.950		314.050	MHz
	Tolerance from 314.000 MHz					
	Δf <sub>C</sub>	2, 3, 4, 5			±50	kHz
Insertion Loss	IL	2, 5, 6		0.8	1.5	dB
Quality Factor	Unloaded Q	Q <sub>U</sub>		18,200		
	50 Ω Loaded Q					
	Q <sub>L</sub>	5, 6, 7		1,500		
Temperature Stability	Turnover Temperature	T <sub>O</sub>	10	25	40	°C
	Turnover Frequency	f <sub>O</sub>				
	Frequency Temperature Coefficient	FTC				
				0.032		ppm/°C <sup>2</sup>
Frequency Aging	Absolute Value during the First Year	fA	1	≤10		ppm/yr
DC Insulation Resistance between Any Two Terminals		5	1.0			MΩ
RF Equivalent RLC Model	Motional Resistance	R <sub>M</sub>	5, 6, 7, 9	10	19	Ω
	Motional Inductance	L <sub>M</sub>		80.9315		μH
	Motional Capacitance	C <sub>M</sub>		3.17441		fF
	Shunt Static Capacitance	C <sub>O</sub>		2.7	3.0	3.3
Test Fixture Shunt Inductance	L <sub>TEST</sub>	2, 7		90		nH
Lid Symbolization (in Addition to Lot and/or Date Code)	135					



**CAUTION: Electrostatic Sensitive Device. Observe precautions for handling.**

#### Notes:

1. Lifetime (10 year) frequency aging.
2. The center frequency, f<sub>C</sub>, is measured at the minimum insertion loss point, IL<sub>MIN</sub>, with the resonator in the 50 Ω test system (VSWR ≤ 1.2:1). The shunt inductance, L<sub>TEST</sub>, is tuned for parallel resonance with C<sub>O</sub> at f<sub>C</sub>.
3. One or more of the following United States patents apply: 4,454,488 and 4,616,197.
4. Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
5. Unless noted otherwise, case temperature T<sub>C</sub> = +25°C±2°C.
6. The design, manufacturing process, and specifications of this device are subject to change without notice.
7. Derived mathematically from one or more of the following directly measured parameters: f<sub>C</sub>, IL, 3 dB bandwidth, f<sub>C</sub> versus T<sub>C</sub>, and C<sub>O</sub>.
8. Turnover temperature, T<sub>O</sub>, is the temperature of maximum (or turnover) frequency, f<sub>O</sub>. The nominal frequency at any case temperature, T<sub>C</sub>, may be calculated from: f = f<sub>O</sub> [1 - FTC (T<sub>O</sub> - T<sub>C</sub>)<sup>2</sup>].
9. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C<sub>O</sub> is the static (nonmotional) capacitance between the two terminals measured at low frequency (10 MHz) with a capacitance meter. The measurement includes parasitic capacitance with "NC" pads unconnected. Case parasitic capacitance is approximately 0.05 pF. Transducer parallel capacitance can be calculated as: C<sub>P</sub> ≈ C<sub>O</sub> - 0.05 pF.

## SAW Resonator

A schematic diagram of a rectangular chip. It features four terminals: one at the top center labeled 'Terminal', one at the bottom center labeled 'Terminal', one on the left side labeled 'NC', and one on the right side labeled 'NC'. Each terminal is represented by a shaded rectangular area with a semi-circular cutout on the chip's perimeter.

**ELECTRICAL TEST**

The diagram shows a circuit for an electrical test. A central component, a parallel LC resonant circuit, is connected to two 50 Ω network analyzers. The resonant circuit consists of an inductor and a capacitor in parallel. The inductor is represented by a coil with a diagonal arrow through it, and the capacitor is represented by two parallel plates. The network analyzers are labeled "From 50 Ω Network Analyzer" and "To 50 Ω Network Analyzer". Below the main circuit, there is a ground reference line with two vertical lines extending upwards to the circuit nodes, indicating a common ground.

50  $\Omega$  Source at  $F_C$

$P_{\text{INCIDENT}}$

$P_{\text{REFLECTED}}$

Low-Loss Matching Network to 50  $\Omega$

Terminal

NC

Terminal

NC

ROXXXXA  
Bottom View

The diagram shows an equivalent circuit for a parallel plate capacitor. It consists of a central parallel combination of two capacitors: a top capacitor labeled  $0.05 \text{ pF}^*$  and a bottom capacitor labeled  $C_p$ . This parallel combination is connected in series with a resistor  $R_m$ , an inductor  $L_m$ , and a capacitor  $C_m$  on the bottom line. The top line is a simple wire. To the right of the circuit, the text  $C_0 = C_p + 0.05 \text{ pF}$  is shown, followed by a note  $^* \text{Case Parasitics}$ .

(4 Places)

Typical Dimension:  
0.010 to 0.047 inch  
(0.25 to 1.20 mm)

**Top View**

Dimensions: A, B, C, D, E, F, G, H, I, J, K, L, M, N, O, P, Q, R, S, T, U, V, W, X, Y, Z.

(Lid Only)

**Side View**

Dimensions: A, B, C, D, E, F, G, H, I, J, K, L, M, N, O, P, Q, R, S, T, U, V, W, X, Y, Z.

**Bottom View**

Dimensions: A, B, C, D, E, F, G, H, I, J, K, L, M, N, O, P, Q, R, S, T, U, V, W, X, Y, Z.

No Connection (2 Places)

**Terminal Detail (2 Places)**

Dimensions: A, B, C, D, E, F, G, H, I, J, K, L, M, N, O, P, Q, R, S, T, U, V, W, X, Y, Z.

45°

Page 2 of 2